



US008221179B2

(12) **United States Patent**
Eden et al.

(10) **Patent No.:** **US 8,221,179 B2**
(45) **Date of Patent:** **Jul. 17, 2012**

(54) **METHOD OF MAKING ARRAYS OF THIN SHEET MICRODISCHARGE DEVICES**

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(*) Notice: Subject to any disclaimer, the term of this patent is extended or adjusted under 35 U.S.C. 154(b) by 611 days.

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(21) Appl. No.: **11/981,412**

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(22) Filed: **Oct. 31, 2007**

(65) **Prior Publication Data**

US 2008/0119105 A1 May 22, 2008

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Related U.S. Application Data

(60) Continuation of application No. 11/070,100, filed on Mar. 1, 2005, now Pat. No. 7,638,937, which is a division of application No. 10/782,164, filed on Feb. 19, 2004, now Pat. No. 6,867,648, which is a division of application No. 10/040,300, filed on Oct. 26, 2001, now Pat. No. 6,695,664.

(57) **ABSTRACT**

The cavity **102** defines an empty volume formed in the insulator **108** has its walls defined by the insulator **108** and may extend through either (or both) the first electrode **106** or the second electrode **104**, in which case the first electrode and/or second electrode also define the walls of the cavity **102**. The cavity **102** is preferably cylindrical and has a diameter of 0.1 μm –1 mm. More preferably, the diameter ranges from 0.1 μm –500 μm , 1 μm –100 μm , or 100 μm –500 μm . The cavity **102** will be filled with a gas that contacts the cavity walls, fills the entire cavity **102** and is selected for its breakdown voltage or light emission properties at breakdown. Light is produced when the voltage difference between the first electrode **106** and the second electrode **104** creates an electric field sufficiently large to electrically break down the gas (nominally about 10^4 V-cm). This light escapes from the microcavity **102** through at least one end of the cavity **102**.

(51) **Int. Cl.**
H01J 17/49 (2012.01)

(52) **U.S. Cl.** **445/25**; 313/582

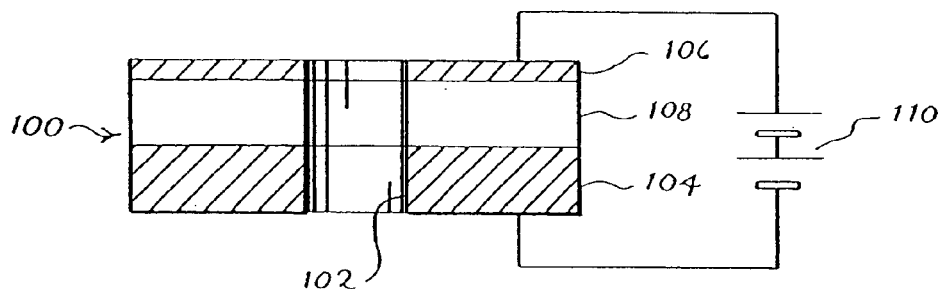
(58) **Field of Classification Search** 445/24–25;
313/582–587, 498–512
See application file for complete search history.

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21 Claims, 4 Drawing Sheets



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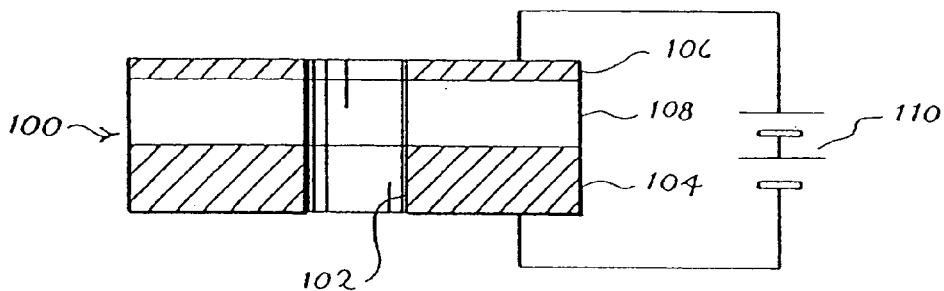


Fig. 1

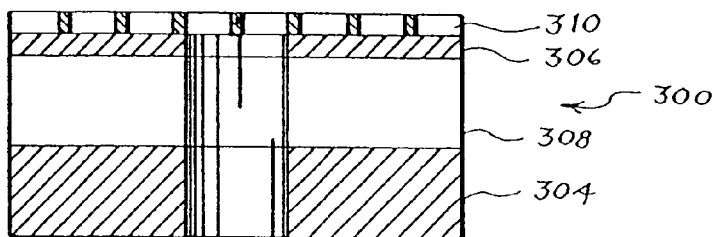


Fig. 6A

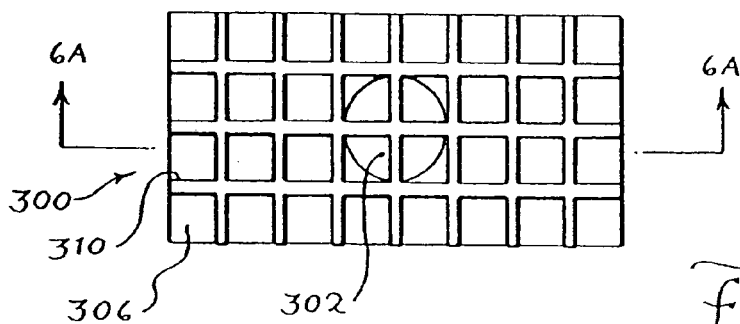


Fig. 6B

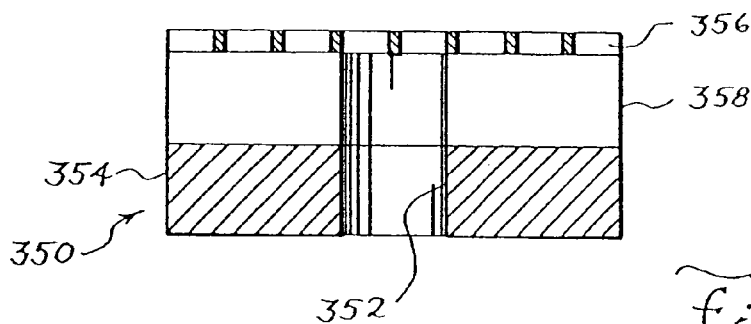
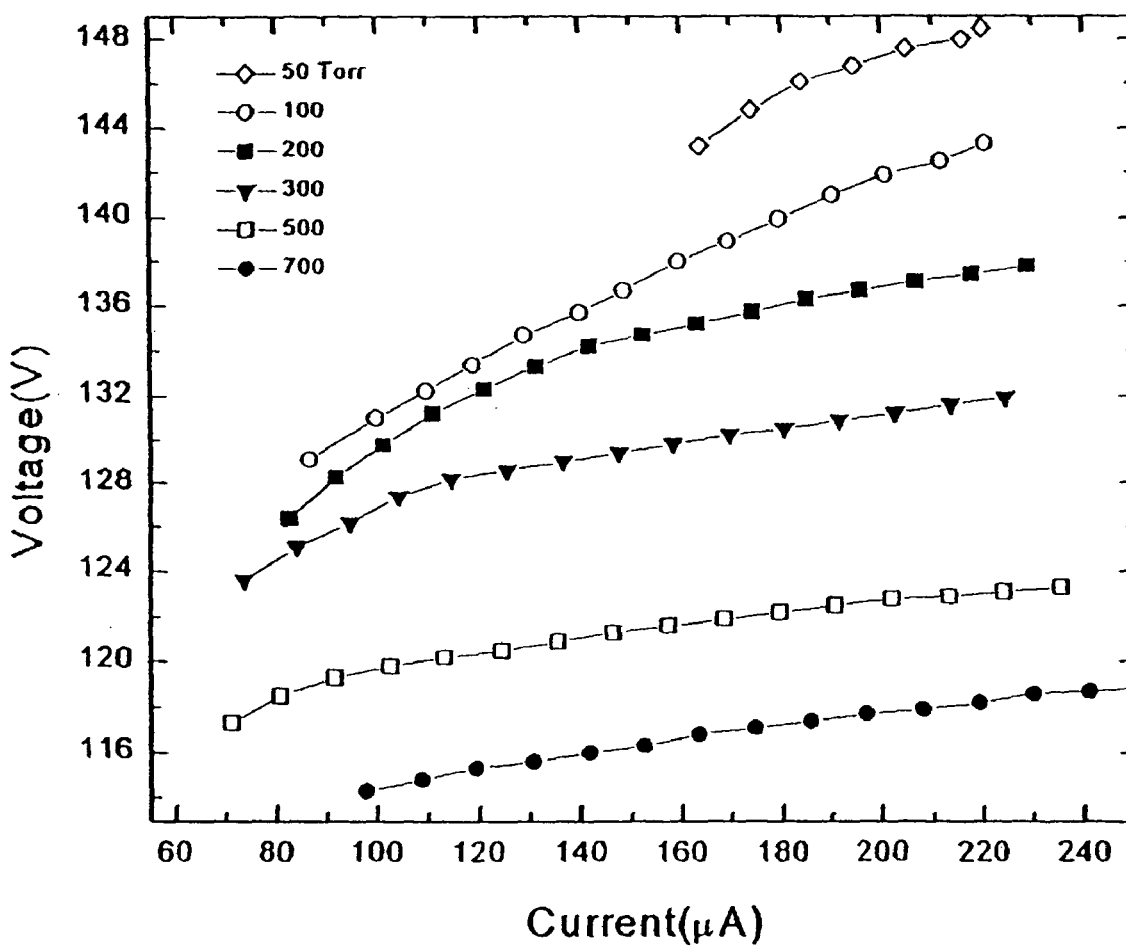


Fig. 6C

*Fig. 2*

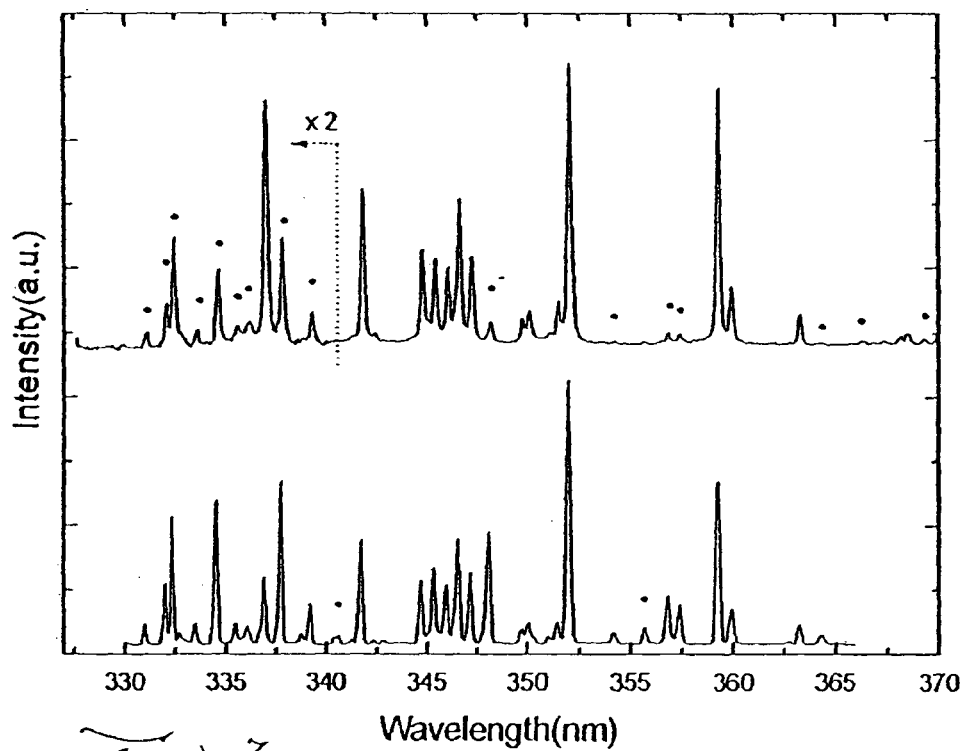
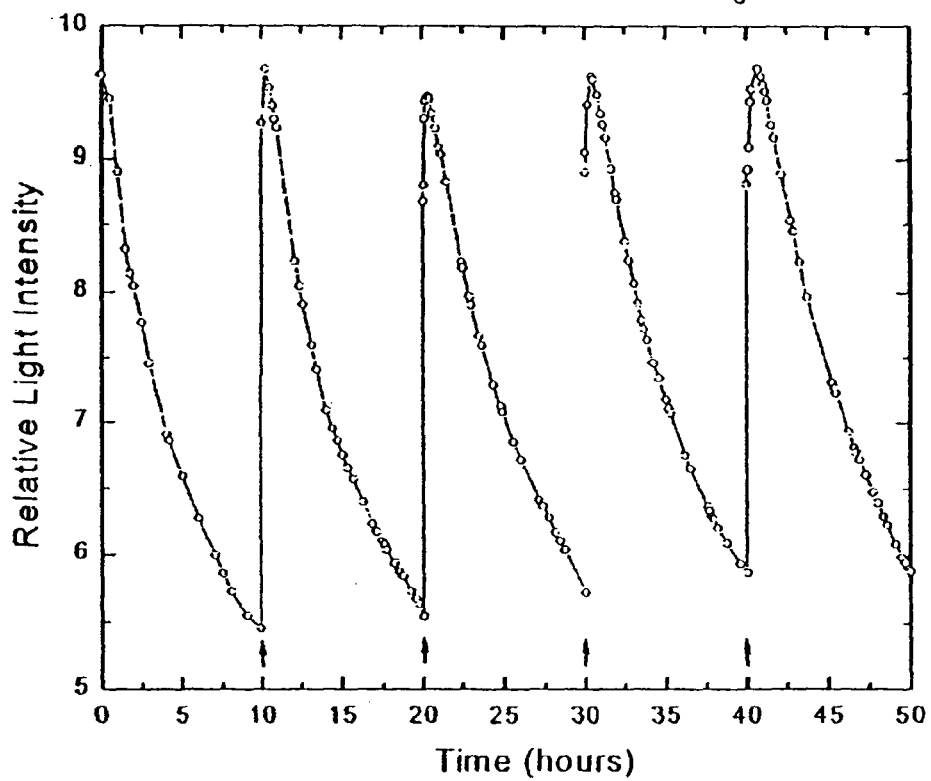


Fig. 3

Fig. 4



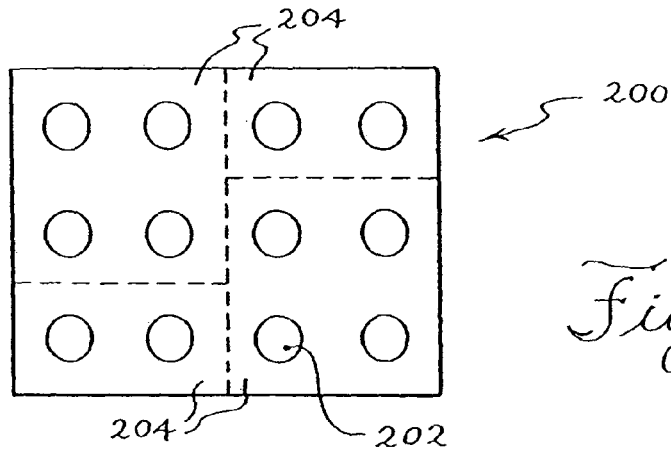


Fig. 7

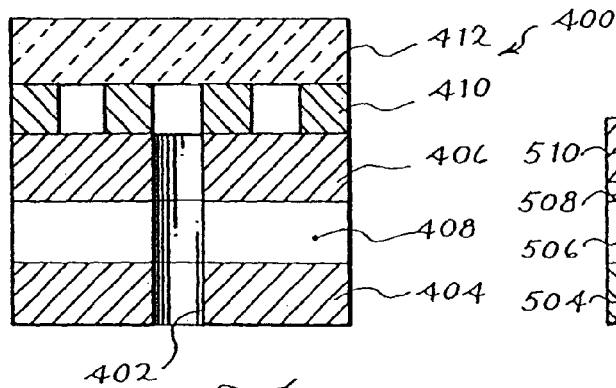


Fig. 8

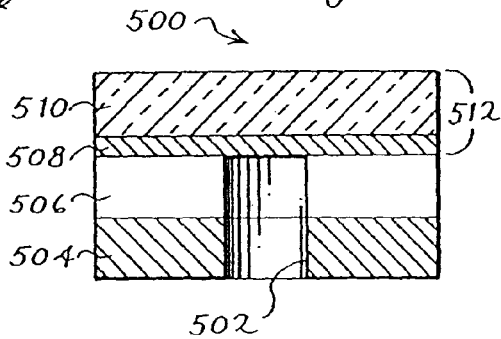


Fig. 9A

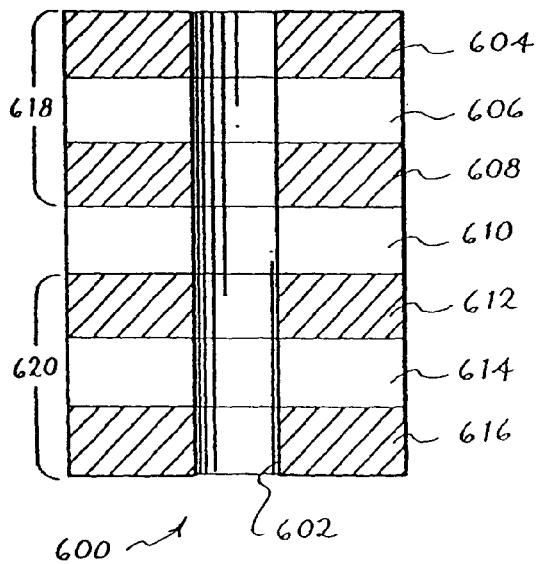
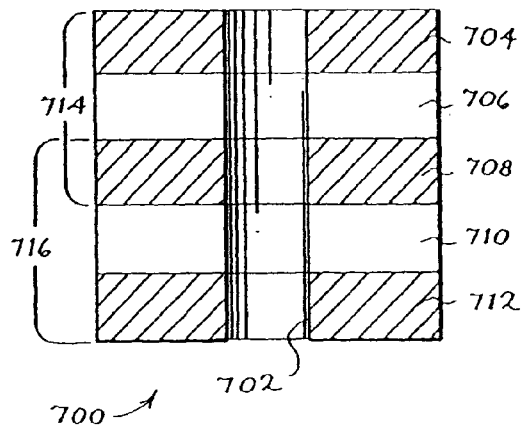


Fig. 9B



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METHOD OF MAKING ARRAYS OF THIN SHEET MICRODISCHARGE DEVICES

PRIORITY CLAIM AND REFERENCE TO RELATED APPLICATIONS

This patent application is a continuation of U.S. patent application Ser. No. 11/070,100 filed Mar. 1, 2005 now U.S. Pat. No. 7,638,937, which is a divisional of U.S. patent application Ser. No. 10/782,164 filed Feb. 19, 2004, now U.S. Pat. No. 6,867,548 issued Mar. 15, 2005, which is a divisional of U.S. patent application Ser. No. 10/040,300 filed Oct. 26, 2001, now U.S. Pat. No. 6,695,664 issued Feb. 24, 2004, all of which are hereby incorporated in entirety.

STATEMENT OF GOVERNMENT INTEREST

This invention was made with government support under Contract Number F49620-98-1-0030 awarded by the U.S. Air Force Office of Scientific Research (AFOSR). The Government has certain rights in the invention.

BACKGROUND

The present invention relates to microdischarge devices and, in particular, new structures for light emitting devices and low-cost methods of producing ultraviolet or visible light from thin sheets.

It has long been known that electrical discharges are efficient sources of light and, today, gas discharge lamps (including fluorescent sources, and metal-halide, sodium, or mercury arc lamps) account for most of the world's light-generating capacity (several billion watts on a continuous basis). Most of these devices are, unfortunately, bulky and frequently have fragile quartz or glass envelopes and require expensive mounting fixtures. In addition to general lighting, discharges produce ultraviolet and visible light for other purposes such as germicidal applications (disinfecting surfaces and tissue), cleaning electronic and optical surfaces in manufacturing, and activating light-sensitive molecules for medical treatments and diagnostics.

Although microdischarges were demonstrated by A. D. White in 1959, only recently were microdischarge devices fabricated in silicon by techniques developed in the integrated-circuit industry. As described in U.S. Pat. No. 6,016,027, the first microdischarge devices made in silicon had a cylindrical microcavity that served as the cathode of the device. The semiconductor cathode was affixed to a copper heat sink with conductive epoxy. The anode for the microdischarge device was typically a metal film such as Ni/cr. A thin dielectric layer deposited onto the silicon electrically insulates the cathode from the anode. When the microcavity is filled with the desired gas and the appropriate voltage imposed between the anode and cathode, a discharge is ignited in the microcavity.

Microdischarges have several distinct advantages over conventional discharges. Since the diameter of single cylindrical microdischarge devices, for example, is typically less than 400-500 μm , each device offers the spatial resolution that is desirable for a pixel in a display. Also, the small physical dimensions of microdischarges allows them to operate at pressures much higher than those accessible to conventional, macroscopic discharges. When the diameter of a cylindrical microdischarge device is, for example, on the order of 200-300 μm or less, the device will operate at pressures as high as atmospheric pressure and beyond. In contrast, standard fluo-

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rescent lamps, for example, operate at pressures typically less than 1% of atmospheric pressure.

Despite their applications in several areas, including optoelectronics and sensors, silicon microdischarge devices have several drawbacks. For example, the annular metal anodes used in early microdischarge devices have short lifetimes because of sputtering. After operating for as little as several hours, damage to the anode is visible and devices frequently fail after only tens of hours of operation. Optical emission from metal atoms evaporated from the anode is easily detected prior to failure of the device. One solution is to replace the metals tested to date with a more robust material, such as polycrystalline silicon or tungsten. However, these materials increase the fabrication cost and difficulty, do not yield significantly increased output power and may not yield significantly improved device lifetime.

Furthermore, silicon is brittle, comparatively high in cost, and single wafers are limited in size (12" in diameter currently). In addition, silicon fabrication techniques, although well-established, are labor and time intensive and, therefore, not suitable for low-cost applications. Therefore, a number of potential applications of microdischarge devices, not presently accessible with silicon (or other) semiconductor technology, could be pursued if low-cost, flexible microdischarge arrays, requiring voltages no higher than that available in common wall sockets, were available.

Two other drawbacks of previous microdischarge devices and arrays concern the inefficiency of extracting optical power from deep cylindrical cavities and the difficulty in scaling the size of arrays. If the cylindrical cathode for a microdischarge is too deep, it will be difficult for photons produced below the surface of the cathode to escape. Another problem arises in fabricating arrays of microdischarge devices is that devices at the perimeter of the array ignite preferentially and arrays as small as 10 \times 10 are difficult to ignite at all.

SUMMARY OF THE INVENTION

The invention provides methods of making arrays of thin sheet microdischarge devices. In a preferred method of fabricating an array of microdischarge devices, a multi-layer dielectric layer thin sheet is positioned with respect to a first thin electrode. A second electrode thin sheet is joined on the dielectric layer sheet. An array of microcavities is provided through at least a portion of the dielectric layer sheet. The method can produce thin large arrays inexpensively. In preferred embodiments, each of the multi-layer dielectric layer thin sheet, the first thin electrode and the second electrode thin sheet have a thickness of less than less than 100 μm . In preferred embodiments, the multi-layer dielectric is formed of polymer, and in other embodiments from oxides and/or nitrides. In a particular preferred embodiment, the multilayer dielectric is formed from oxide and nitride films.

BRIEF DESCRIPTION OF THE DRAWINGS

FIG. 1 is a sectional illustration of an embodiment of the present invention;

FIG. 2 shows V-I characteristics of an embodiment of the present invention;

FIG. 3 compares the ultraviolet emission spectrum for an embodiment of the present invention with that of a silicon microdischarge device;

FIG. 4 shows data obtained for an embodiment of the present invention obtained over a period of 50 hours;

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FIG. 5 is a top view of an embodiment of the present invention;

FIG. 6A is a sectional view of an embodiment of the present invention;

FIG. 6B is a top view of an embodiment of the present invention;

FIG. 6C is a sectional view of an embodiment of the present invention;

FIG. 7 is a sectional illustration of an embodiment of the present invention;

FIG. 8 is a sectional illustration of an embodiment of the present invention;

FIG. 9A is a sectional illustration of an embodiment of the present invention; and

FIG. 9B is a sectional illustration of an embodiment of the present invention.

DETAILED DESCRIPTION OF THE PREFERRED EMBODIMENTS

The invention provides methods of making arrays of thin sheet microdischarge devices. In a preferred method of fabricating an array of microdischarge devices, a multi-layer dielectric layer thin sheet is positioned with respect to a first thin electrode. A second electrode thin sheet is joined on the dielectric layer sheet. An array of microcavities is provided through at least a portion of the dielectric layer sheet. The method can produce thin large arrays inexpensively. In preferred embodiments, each of the multi-layer dielectric layer thin sheet, the first thin electrode and the second electrode thin sheet have a thickness of less than less than 100 μm . In preferred embodiments, the multi-layer dielectric is formed of polymer, and in other embodiments from oxides and/or nitrides. In a particular preferred embodiment, the multilayer dielectric is formed from oxide and nitride films.

The present invention provides microdischarge devices and arrays of microdischarge devices that are inexpensive to manufacture and have electrical and optical characteristics that are superior to previous microdischarge devices. These microdischarge devices and arrays may operate at atmospheric pressure and at voltages of 120V or less, and preferably at voltages of not greater than 100V. Either direct current (DC) or alternating current (AC) voltages may be applied to the electrodes. The microdischarge devices and arrays of microdischarge devices may also be flexible.

An embodiment of a microdischarge device (not drawn to scale) is shown in FIG. 1. The microdischarge device 100 includes a first electrode 106, a second electrode 104 and a dielectric layer 108 (also called an insulating layer or an insulator) disposed between the first electrode 106 and second electrode 104. A cavity 102 is formed in the insulator 108 and may be additionally formed in either or both of the first electrode 106 and the second electrode 104 such that the openings or holes in each of the first electrode 106, insulator 108, and second electrode 104 are aligned with each other. The cavity 102 preferably has a substantially cylindrical shape to more easily couple to optical fiber, for example, and is formed in a direction transverse to the planes containing the electrodes 104 and 106 and insulator 108. The first electrode 106 and second electrode 104 are both electrically and thermally conductive and a potential difference across the insulator 108 is established by a voltage source 110 connected between the first electrode 106 and the second electrode 104. The potential difference creates a discharge in the cavity 102 when a gas is present. The resulting light has emission spectra that are characteristic of the gas selected. This light is subsequently emitted from at least one end of the cavity 102.

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The first electrode 106 and second electrode 104 preferably serve to establish the potential difference across the insulator 108 and thereby energize the microdischarge device 100. Thus, the first electrode 106 and second electrode 104 are fabricated from materials having good electrical and thermal conductivity. The first electrode 106 and second electrode 104 may be planar and may be fabricated from thin layers of conductive material, preferably having a thickness of less than 100 μm , more preferably thicknesses from about 10 \AA -10 μm and from 50 \AA -5 μm . Common metals that may be used to form the electrodes include copper, aluminum, gold, silver, nickel, and zinc and alloys thereof. Other conductors include polymers containing carbon black and other conducting polymer materials or highly doped crystalline, polycrystalline or amorphous semiconductor films. Alternatively, rather than the electrodes being formed from an optically opaque material, at least one of the electrodes may be fabricated from a solid layer of optically transmissive material that does not significantly absorb light at the wavelength of the discharge, such as indium tin oxide (ITO). Optically transmissive material transmits preferably at least 50% of the light impinging substantially normal to the surface of the material at wavelength emitted by the discharge. More preferably, the optically transmissive material transmits at least 60%, 70%, 80%, 90%, or even 95% of the light impinging substantially normal to the surface of the material at a wavelength emitted by the discharge. The first electrode 106 and second conducting electrode 13 preferably form a cathode and an anode.

At least one of the electrodes is preferably deposited, plated, or otherwise disposed onto the dielectric layer to establish a film of conducting material around the rim of the cavity in the dielectric layer. Furthermore, although not shown, at least one of the electrodes may be fabricated from multiple layers, at least one of which (preferably the layer closest to the discharge) is electrically conducting. The other layers may serve as a mirror to reflect light of undesired wavelengths back into the microdischarge.

The first electrode 106 may additionally act as a support for the microdischarge device 100. One example of such a structure would be using Kapton onto which a thin conducting film is deposited or a foil is in contact.

The second electrode 104 is preferably thinner than the first electrode 106. The insulator 108 is formed of a material having a resistivity of at least 0.1 $\Omega\text{-cm}$, preferably from 0.5 $\Omega\text{-cm}$ -100 $\Omega\text{-cm}$ or from 1.0 $\Omega\text{-cm}$ -10.0 $\Omega\text{-cm}$.

The insulator 108 acts as a dielectric layer to electrically isolate the first electrode 106 and second electrode 104 of the microdischarge device 100. Preferably, the insulator 108 has excellent thermostability and high dielectric strength, e.g. $T_g > 200^\circ\text{C}$. and at least 10^4 V-cm , respectively. More preferable ranges for the thermostability include $400^\circ\text{C} > T_g > 250^\circ\text{C}$. and $350^\circ\text{C} > T_g > 275^\circ\text{C}$. and for the dielectric strength from $5 \times 10^4\text{ V-cm}$ - $5 \times 10^6\text{ V-cm}$ or 10^5 V-cm - $5 \times 10^5\text{ V-cm}$.

The insulator 108 may be a polymer such as polyimide, which has exceptional thermostability and dielectric strength. For example, the breakdown voltage for a polyimide film about 5 μm thick is approximately 1.2 kV, giving a dielectric strength in excess of 10^6 V-cm . Other dielectrics, resins and polymers—for example, oxide and nitride films such as metal oxides, SiO_2 , Si_3N_4 or KAPTON—may be used as long as the material retains its insulation properties at the material thickness required for adequate dielectric strength. Furthermore, multiple films of different materials (having different dielectric constants) may be used to fabricate the insulator in order to improve both individual device and array performance. Tests have shown that a multiple layer dielectric (containing, for example, $\sim 0.5\text{ }\mu\text{m}$ Si_3N_4 , $0.5\text{ }\mu\text{m}$ SiO_2 , and several

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microns of polyimide) not only improves the voltage-current characteristics of an individual microdischarge device but also makes it possible to realize stable operation of large arrays (for example, 30×30) of devices. If, on the other hand, the insulator **108** is a single film of polyimide, for example, it is difficult to operate arrays larger than approximately 5×5.

The insulator **108**, in addition to the first electrode **106** and second electrode **104**, may also be thin, preferably less than 100 μm. Preferred thickness ranges for the insulator **108** may be from 10 Å–100 μm or 100 Å–10 μm. The voltage applied between the first electrode **106** and second electrode **12** to create the discharge is directly related to the thickness of the dielectric layer **108**; as well as the particular gas and gas pressure in the cavity. Scaling the thickness of the insulator **108** thus changes the magnitude of the operating voltage of the microdischarge device **100**. Some applications may additionally require fabrication of the first electrode **106**, insulator **108**, and second electrode **104** using materials that have appropriate conductive/dielectric properties at the desired device thicknesses.

The cavity **102** formed in the insulator **108** may extend through either (or both) the first electrode **106** or the second electrode **104**. The cavity **102** is preferably cylindrical and has a diameter of 0.1 μm–1 mm. More preferably, the diameter ranges from 0.1 μm–500 μm, 1 μm–100 μm, or 100 μm–500 μm. The cavity **102** will be filled with a gas selected for its breakdown voltage or light emission properties at breakdown. Light is produced when the voltage difference between the first electrode **106** and the second electrode **104** creates an electric field sufficiently large to electrically break down the gas (nominally about 10⁴ V-cm). This light escapes from the microcavity **102** through at least one end of the cavity **102**.

The gas that fills the cavity **102** may be selected for its light emission properties. The term gas herein refers to acceptable single gases, gas mixtures, and vapors. Examples of common gases that work well alone are the rare gases (He, Ne, Ar, Xe, and Kr), N₂, and air. A wide variety of gas mixtures also produce intense emission from atomic or molecular species. An example of the former is Ar/Hg vapor and the latter includes rare gas/halogen donor gas mixtures (such as one or more rare gases mixed with F₂, NF₃, XeF₂, N₂F₄, HCl, Cl₂, I₂, HI or other halogen-bearing molecules). Another example is the XeO (xenon oxide) excimer that is produced in mixtures of Xe and O₂, N₂O or NO₂ gases. Such gases, however, need not be present in the channel: breakdown may occur when air is present.

The microdischarge device **100** may be less than 50 μm thick (approximately two one-thousandths of an inch), thus giving rise to a thinner device than is typical of conventional microdischarge devices. One feature of arrays of such devices is that the finished array may be flexible and light. Thus, these arrays are able to conform to various shapes and can, if desired, be rolled into a tube. This feature enhances the portability and utility of microdischarge arrays.

The possible radius of curvature of the microdischarge device **100** (or array of devices) may be much smaller than that of conventional brittle silicon-based microdischarge devices. For comparison, the radius of curvature of a silicon wafer is several meters while that of an adult human arm is approximately five cm. The realizable radius of curvature of the microdischarge device **100**, is preferably from several meters to less than a single mm. For flexible microdischarge devices, the realizable radius of curvature may be substantially less, preferably between 1 cm and 1 m or 10 cm and 100 cm. Thus, a feasible radius of curvature of an array of microdischarge devices may be that of human limbs or smaller. In a group of these flexible discharge devices (either a planar

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array or stack), when first bent by less than the maximum possible radius of curvature, a substantial percentage of the discharge devices should continue to operate. Preferably, the device failure rate should not significantly change when bending the array as long as the operating conditions remain the same. This is not to say that problems such as fractures will not appear in the devices, but only that the operating characteristics (e.g. voltage, current, emission intensity) should not decrease beyond acceptable levels. For the purposes of the specification and claims herein, the radius of curvature is defined as the minimum radius of curvature to which the device is able to be bent before the device failure rate rises beyond acceptable levels, preferably above 50%. Alternatively, the radius of curvature may be defined as the minimum radius of curvature to which the device is able to be bent before a specific percentage of the devices in an array fail. Preferably fewer than 50% of the devices fail to insure adequate operation when used during therapeutic treatment, for example; more preferably fewer than 20%, 10%, 5%, 2%, or even 1% fail.

One method of fabrication of the microdischarge device **100** is to mechanically assemble the various layers that comprise the microdischarge device **100**. Thus, assembly begins with individually positioning the first electrode **106**, insulator **108** and second electrode **104** on each other and then forming the cavity **102** in the assembled layers by any of several processes such as mechanical or ultrasonic drilling, optical drilling (preferably by a pulsed laser), dry etching or wet chemically etching. These techniques are all well developed in the semiconductor industry. In an alternate method of fabrication, holes may be formed in the insulator **108** and either (or both) of the first electrode **106** and second electrode **104**. After forming the hole(s), the first electrode **106**, insulator **108** and second electrode **104** may be assembled such that the insulator **108** is sandwiched by the first electrode **106** and second electrode **104**. Preferably, the layers are positioned such that the holes in the layers coincide to form the cavity **102**.

In another method of fabrication, the first electrode **106** may be positioned and the insulator **108** formed on the first electrode **106**. The insulator **108** may be fabricated by spin coating or otherwise depositing a film on the first electrode **106**. The second electrode **104** is subsequently deposited on the insulator **108**. The cavity **102** is then preferably formed through the insulator **108** and at least one of two electrodes **11** and **13**.

Alternatively, the first electrode **106** may preferably be deposited onto an insulating substrate (not shown), which provides a supporting surface for first electrode **106**. The insulator **108** and second electrode **104** may next be fabricated as above, i.e. spin coating and subsequent deposition, and then the cavity **102** formed. In this case, the first electrode **106** may either be temporarily attached to the insulating substrate and the insulating substrate removed after assembling the layers or the first electrode **106** may be permanently attached to the insulating substrate. In either case, the cavity **102** may be formed through the insulating substrate (if present), the first electrode **106**, and the insulator **108** after the layers are assembled. Similarly, the cavity **102** may be formed through the second electrode **104** and the insulator **108** after the layers are assembled, whether or not the insulating substrate is present.

In an embodiment in which the insulating substrate permanently covers the cavity **102**, the insulating substrate may preferably comprise an optically transmissive material. However, for embodiments in which the insulating substrate is temporarily attached to the first electrode **106** or in which the

cavity **102** is formed through the insulating substrate, the insulating substrate may comprise any suitable insulating material. An example of such an insulating substrate may be poly(pyromellitimido-1,1',4,4'-diphenylene ether), also known as PMDA-ODA poly(pyromellitimido-oxydianiline) or KAPTON.

Other methods for forming the first electrode **106** on the insulating substrate include evaporation, growth, sputtering, deposition, or attaching with conductive paste. Similar methods may be used for forming the insulator **108** on the first electrode **106** and for forming the second electrode **104** on the insulator **108**. Examples of methods for forming the cavity **102** include mechanical drilling, optical drilling preferably by a pulsed laser, and chemically etching the different layers.

After the second electrode **104**, insulator **108** and first electrode **106** have been assembled and the cavity **102** formed, the cavity **102** may then be filled with a specified amount or pressure of a selected gas. Light produced by a discharge in the gas is emitted from the opening of the cavity **102**. Additionally, the cavity **102** may be sealed while containing the desired gas at the proper pressure by laminating or bonding a plastic sheet, glass, quartz or mica (not shown) on to both sides of the microdischarge array assembly, thereby sealing the microdischarge device **100** while still allowing the generated light to pass through the sealing material. Thus, an optically transmissive material may be used to seal the cavity **102** of the microdischarge device **100**. Preferably, the sealing material may be flexible in addition to being optically transmissive.

Sealing of the microdischarge cavity while containing the desired gas at the proper pressure may be performed in a number of ways other. One method is to "hard seal" the array of microdischarge electrodes and insulator to a quartz window having a conducting film (such as ITO) or a fine metal grid on one side. The bonding process takes place with the conductor facing the electrode and bonding occurs along the entire perimeter of the electrode and quartz. When completed, this structure is robust and compact, requiring only electrical connections to an appropriate power supply. Another approach using flexible optically transmissive material is to laminate an array of electrode/insulator/electrode (or screen) devices. By laminating a plastic sheet on both sides of the microdischarge array assembly, light generated within the array will be transmitted by the packaging if the laminating sheet material is chosen properly. A phosphor/electroluminescent material may also be included on the screen before sealing.

To operate the microdischarge device **100**, a voltage is applied between the first electrode **106** and second electrode **104**, which produce a discharge in the gas in the cavity **102**. The resulting light produces emission spectra that are characteristic of the gas or gas mixture selected. This light is subsequently emitted from at least one end of the cavity **102**.

EXAMPLES

One example of such a microdischarge device **100** has a 25 μm thick copper foil as the first electrode **106**, a polyimide film 5-8 μm thick as the insulator **108**, and a 2000 Å thick Ni film as a second electrode **104**. FIG. 2 shows the voltage-current (V-I) characteristics for this Ni/polyimide/Cu microdischarge device. The polymer film for the insulator **108** was formed by spin coating a solution of 20 wt % of poly(trimetallic anhydride chloride-alt benzidine) in a 1-methyl-2-pyrrolidinone/xylene solution on the copper foil. Residual solvent was evaporated by a hot plate and a vacuum drying process at $>200^{\circ}\text{C}$. The Ni second electrode **104** was next

evaporated onto the polymer, giving a total device thickness of about 30 μm . Microdischarge cavities **14** having a diameter of typically 150 μm were then produced either by mechanically drilling or using a pulsed Ti:Al₂O₃ laser to bore through the second electrode **104**, insulator **108** and first electrode **106**. Once fabricated, the microdischarge device **100** was evacuated to about 10^{-6} Torr by a turbomolecular pump. The polymer was subsequently vacuum baked to minimize possible outgassing by the polymer and then backfilled with the desired gas, Ne. By observing the emission spectrum of a rare gas produced by the microdischarge device **100**, freedom from (or the presence of) hydrocarbon impurities was determined.

The positive differential resistance of tested microdischarge devices was 30 k Ω -120 k Ω depending on the gas pressure in the cavity **102** (100 Torr to 700 Torr, respectively). These differential resistances are comparable to conventional planar silicon microdischarge devices, as shown in FIG. 2. However, unlike the conventional planar silicon microdischarge devices, which typically work at gas pressures considerably less than one atmosphere and require at least 200 V to operate, the microdischarge device **100** operates both at gas pressures approaching one atmosphere and voltages at or below 120 V. Furthermore, although the data of FIG. 2 were obtained for a polyimide thickness of about 5 μm , the operating voltages vary with the thickness of the polyimide layer in a roughly proportional manner. For example, tested microdischarge devices with polyimide layer thicknesses of about 7 μm and 10 μm exhibit operating voltages of about 180 V and 250 V, respectively, and, thus, thinner polyimide films (i.e., <5 μm) should yield operating voltages well below 100 V.

The device of FIGS. 1 and 2 operates in a manner similar to that of conventional metal/SiO₂/silicon devices. FIG. 3 illustrates a comparison of a portion of the ultraviolet emission spectrum (320-370 nm) produced from neon gas for the above Ni/polyimide/Cu foil device with that of a conventional Ni/SiO₂ (20 μm thick)/silicon microdischarge device. The conventional microdischarge device had an overall thickness of 57 μm and a cavity diameter of 180 μm , both somewhat greater than the thickness (30 μm) and diameter (150 μm) of the Ni/polyimide/Cu microdischarge device. The solid dots denote emission lines produced by the singly-charged neon ion (i.e., Ne⁺). Note that the two spectra are virtually identical, showing strong emission from more than 20 Ne ion transitions. The emission intensity of several of the Ne⁺ ion transitions in the Ni/polyimide/Cu device is weaker than the same transitions in the conventional microdischarge device, owing to the smaller depth of the cathode. Nevertheless, the strength of the ion emission lines from the metal/polymer device show that the electron energy distribution has a component that is "hotter" (higher energy) than that for a conventional positive column discharge.

The microdischarge devices are also remarkably robust. The emission intensity as a function of time was measured for a large number of microdischarge devices. FIG. 4 shows lifetime data obtained for a single Ni/polyimide/Cu microdischarge device obtained over a period of 50 hours. This device had a 150 μm diameter cavity and was filled with Ne at a pressure of 300 Torr. The V-I characteristics of the microdischarge device remained stable over the entire 50 hours. Every ten hours, the Ne gas was refreshed due to a decline in intensity caused by the outgassing of the polymer and a small "background" leak in the vacuum system. As shown in FIG. 4, after each refill of Ne gas, the emission intensity of the microdischarge device returned to approximately the initial value, indicating that no device degradation had occurred. Neither the outgassing nor the background leak is a limitation of the

device itself and obtaining lifetimes that exceed several thousand hours is expected to be quite feasible.

For example, a 3×3 array of Ni/polyimide/Cu microdischarge devices operating in 400 Torr of Ne at 4.5 mA and 165 V demonstrated intense emissions that could readily be seen across a well-lit room. However, if one wishes to fabricate large arrays or a collection of microdischarge devices, ohmic losses become a problem. Large arrays often do not ignite uniformly; rather, devices at the perimeter of the array ignite preferentially because of the non-uniformity in the applied voltage difference across different cavities in the array. Large arrays contain at least 10 individual devices, preferably at least 20 individual devices, and more preferably at least 50 or 100 individual devices.

To overcome this problem, another embodiment, shown in FIG. 5, divides the overall array 200 into sub-arrays 204 containing individual devices 202 and delivers power separately to the sub-arrays 204. The sub-arrays 204 may be independently excited or otherwise excited such that the devices 202 no longer ignite preferentially. For example, the sub-arrays 204 may have at most one of the two electrodes in common or may be excited in parallel. Alternatively, the entire array 200 may have multiple conductive leads from the voltage source and provided to selected areas of the array 200 or may have continuous strips of the conductive leads crossing the array 200 in a grid-like manner. Further, each device may be individually excited and ballasted. These arrangements are only examples of techniques that may be used to provide the desired uniformity to the array 200.

Such designs minimize ohmic losses in the electrodes as arrays increase in size and improve the characteristics and reproducibility for igniting the array or collection. In addition, these designs decrease the voltage variation appearing across individual devices in at least 10 of the devices in the array. This decrease is such that when a minimum voltage sufficient to cause discharging of the at least 10 of the devices is applied then the voltage difference between the first and second electrodes at every cavity of the discharge devices has a voltage difference of no more than 20% of the average voltage difference. The lower the voltage difference between a desired set of devices in the array, the better the uniformity in emission. Thus, more preferably the voltage difference may be no more than 10%, 5%, 2%, or 1% of the average voltage difference of at least 10, 20, 50, 100, 1000 or 10,000 devices.

In addition to exciting the sub-arrays independently, using a multiple film dielectric allows one to realize much larger arrays that are well behaved, for the reasons above. The addition of a screen on top of one electrode or replacing one of the electrodes with a screen still further improves device and array characteristics, as discussed below.

Some of the embodiments may be manufactured as single microdischarge devices or arrays of devices by mass production techniques. The materials used in the microdischarge device of these embodiments are thin and inexpensive relative to conventional microdischarge devices. Similarly, the material characteristics of microdischarge devices of the embodiments are thus manufacturable by large-scale processes, unlike arrays of Si-based microdischarge devices, which are limited in size, typically to 12" Si wafers. One example of such a process is a "roll-to-roll" manufacturing process in which individual rolls of the three layers of one embodiment (two laminating layers and the microdischarge layer, including anode, cathode, and dielectric) are assembled into one roll. This assembly would, of course, take place in the presence of the desired gas or gas mixture so that the finished laminated devices would have the proper gas in each micro-

cavity discharge. Also, immediately prior to laminating the devices, the microcavities could be formed by any of several processes, as mentioned before, including laser micromachining. After large sheets of microdischarge devices are fabricated at low cost, these sheets may subsequently be cut into smaller sections and then fitted with electrical connections to be applied to any number of uses.

As described above, a single microdischarge device or arrays of devices having an insulating substrate may also be produced by the same manufacturing processes. More specifically, in large-scale roll-to-roll manufacturing, rolls of metal film forming the first and second electrodes may be assembled on Kapton (as the insulating substrate) and another polymer as the insulator. The cavities may then be machined by imaging laser radiation onto the metal/polymer/metal sandwich through a mask. Such imaging techniques are well-known in the laser micromachining industry. The cavities may also be formed by alternate methods, such as mechanically drilling or punching holes.

To mass-produce the microdischarge devices also may require an inexpensive means of sealing the microdischarge device. As discussed above, the microdischarge device may be sealed by lamination with an optically transmissive material to enclose the cavity containing the gas. The process may include sealing the microdischarge device or array of microdischarge devices between two sheets of optically transmissive material in the presence of the desired gas (in much the same way a driver's license is laminated).

A conventional plastic laminate may be used to seal the device. One problem with this is that the plastic may outgas impurities into the gas and limit the lifetime of the laminated microdischarge device. However, the lifetime the sealing material is not a fundamental limitation on the device lifetime. For example, the lifetime of the microdischarge device will increase when using sealing materials that outgas less. Similarly, depositing a thin transmissive film, such as tantalum oxide or glass, onto conventional laminating sheets will impede or eliminate the outgassing process and extend the lifetime of the microdischarge devices. Another alternative may be a vacuum baking procedure to significantly reduce the outgassing of the conventional laminate sheets.

In another embodiment, illustrated in FIG. 6A, the device 300 includes a conducting screen electrode (or screen) 310 that is in contact with and extends across at least one of the first electrode 304 or the second electrode 306 of the microdischarge device 20. The screen 310 improves both the lifetime and light output of the microdischarge device 300, making it more efficient by allowing the device 300 to operate at lower voltages and producing greater light output power at the same power. The result of this is that the emission intensity of discharge from the end of the cavity 302 in which the screen 310 is present is up to, for example, an order of magnitude larger than the emission intensity when a screen 310 is not present.

The screen 310, as shown in FIG. 6B, preferably has openings that are no larger than the diameter of the cavity 302 of the microdischarge device 300. Preferably, screens 310 are constructed of a metal such as Ni, Au, or Cu, which are available commercially as sample holders for Transmission Electron Microscopy (TEM) and are chosen such that most of the light reaching the screen 310 from the microdischarge passes through the screen 310. The thickness of the screen 310 may range from 10 Å-10 mm, and preferably ranges from 1 µm-500 µm including 10 Å-10 µm, 10 Å-1 µm, and 100 Å-1 µm. Other conductive materials may also be used to form the screen 310, such as ITO, which does not absorb substantially at a wavelength emitted by the discharge. The screen 310 may

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be mounted onto either (or both) the first electrode **304** or second electrode **306**. The screen **310** presents a more uniform electrostatic potential to the discharge in the cavity **302** as the screen **310** covers at least part of the hole in the electrodes **304** and **306**.

Alternatively, FIG. **6C** shows an embodiment of a device **350** in which the conducting screen **356** replaces the second electrode, rather than being disposed on the second electrode. Although FIG. **6C** depicts an embodiment in which the screen **356** replaces the second electrode, as above, the screen **356** may replace the first electrode **354** or screens may replace both electrodes. An insulator **358** is disposed between the screen **356** and the other electrode **354**, with the cavity **352** present as above. One feature of a microdischarge device **300** having a screen **310** is that the emission intensity of light from the end of the cavity **302** in which the screen **310** is present is up to an order of magnitude larger than the emission intensity emerging from the other end of the cavity **302** in which the screen **310** is not present. In one example, a Ni/polyimide/Cu microdischarge array having a Ni screen with 55 μm \times 55 μm square openings and in contact with the second electrode exhibited intense emission and was clearly observed across a well-lit room.

In addition to light being emitted from the cavity, electrons may also be extracted from the cavity of the microdischarge device via the screen electrode, thereby forming a plasma cathode. This may be used in another embodiment, illustrated in FIG. **7**, in which a microdischarge device **400** includes a phosphor or electroluminescent material **412** disposed onto the screen **410**. Although not shown, the phosphor or electroluminescent material **412** may also be disposed onto a non-conducting window adjacent to the screen **410** on the opposing side of the screen **410** as the second electrode **406**. In addition, the phosphor or electroluminescent material **412** may be disposed on both sides of the device **400**.

Thus, in this embodiment, electrons are generated in the cavity **402** by the voltage potential between the second electrode **406** and the first electrode **404**. The majority of the electrons are then extracted from the cavity **402** through the screen **410** and then impinge upon the phosphor or electroluminescent material **412**, which luminesces. As in the embodiment shown in FIG. **6C**, the screen **410** may replace one of the electrodes **404** and **406**, preferably at least the electrode disposed under the phosphor or electroluminescent material **412**. Furthermore, one variation on this embodiment would be to insert a non-conducting layer between the screen **410** and the proximate electrode. This would allow one to operate the microdischarge continuously but illuminate the phosphor **412** only when a voltage pulse is applied between the insulator **408** and the screen **410** that would attract the electrons towards the screen **410**.

An alternative embodiment, in which the second electrode and screen electrode are replaced by a conducting (but optically transmissive) electrode **512**, is shown in the microdischarge device **500** in FIG. **8**. The conducting electrode **512** is a combination of layers that may include a conducting film **508** disposed on a supporting surface **510**. The conducting film **508** is fabricated from at least one material that is both conducting and optically transmissive, such as ITO and is disposed over the entire insulator **506** including the opening to the cavity **502**. The conducting film **508** serves as the second electrode but, in addition, establishes a uniform potential surface for the discharge cavity **502**, similar to the screen of previous embodiments. The supporting surface **510** may be fabricated from at least one optically transmissive material and may be formed from a conducting material. In addition, the material forming the supporting surface **510**

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may act as a combination supporting surface, window, and material sealing the cavity **502**. Examples of acceptable materials used to form the supporting surface **510** include glass, plastics and resin/polymers. Furthermore, window **510** need not be fully transmissive but, for some applications, translucence will suffice. As above, the first electrode **504** may also be replaced by a similar conducting electrode **512**.

A method for fabricating the conducting electrode **512** includes forming the insulator **506** on the first electrode **504** (using one of the methods mentioned above), depositing the conducting film **508** onto the supporting surface **510**, and then sealing the structure by combining these layers. The conducting electrode **512**, containing the conducting film **508**, traverses the entire microdischarge device **500** or array of microdischarge devices and again presents a more uniform potential surface to the discharge cavity **502**. An advantage of this embodiment over the embodiment containing a screen electrode is that the light output of the microdischarge device or array of microdischarge devices is not limited by the openness of the screen.

A number of potential applications of microdischarge technology would become accessible if thin, low cost microdischarge arrays were available. Custom lighting and photodynamic therapy are two such examples of industrial and medical applications that would be ideally suited for such a technology. Photodynamic therapy, for example, is a medical treatment of rapidly growing importance that involves destroying harmful cells in the human bloodstream with light. The target cells are "tagged" with a chromophore (light absorbing molecular ligand) that, after attaching to specific cells in the bloodstream, typically absorbs light strongly in the red or near-infrared, for example, by chemically attaching a chromophore to an antibody specific for the cell. This wavelength range is of particular interest because human skin transmits (passes) light in this spectral region. When the light enters the bloodstream and is absorbed by the chromophore, the cell is destroyed. A thin, low cost, flexible and efficient source of red or near-infrared light would be ideally suited for this application. A flexible sheet of microdischarges, emitting in the red, for example, could be wrapped around the arm of a patient with a VELCRO strip in much the same way that blood pressure is measured. For a predetermined period, such as an hour or two, the patient could read or perform other light activity as the phototherapy is carried out. Once treatment is completed, the light source could be discarded because of its low cost. That is, each patient would be treated with a new "arm wrap" source. Such a product will also have numerous applications in manufacturing (polymer curing, stereolithography), and medicine (germicidal applications, phototherapy, cellular diagnostics).

Another use of multiple microdischarge devices is gas chromatography i.e. the determination of the composition of a gas. In this application, a gas flows laterally between a planar array of microdischarge devices and an opposing planar array of detectors. Each detector has an optical axis that coincides with the corresponding microdischarge device and has a filter that transmits a particular wavelength or set of wavelengths (i.e. a bandpass, low-pass or high-pass filter). Only particular wavelengths are transmitted by the gas, while others are absorbed. Thus, each detector detects light of a particular wavelength generated by the microdischarge devices and that passes through the gas present. As the gas to be tested enters each microdischarge, it is energized (excited) and emits light at wavelengths characteristic of the particular gas. Each detector, then, would observe a particular wave-

length region, enabling the composition of the gas flow stream (or the presence of impurities in the gas flow stream) to be determined.

One method to determine the composition is to have the planar array emit light of a broad set of wavelengths and vary the filters of the corresponding detectors. Another method to determine the composition is to vary the wavelength of the light emitted from the microdischarge devices in the planar array, perhaps by varying the gas that fills the microdischarge devices, and having the same filter for each corresponding detector. In either case, data are collected and the composition of the gas determined from the transmission/absorption spectra of the gas. The microdischarge devices may emit either incoherent light (such as the custom lighting arrays above) or coherent light (as described by the microlasers described below). Alternately, these methods may be combined—that is, various sets of microdischarge devices in the array could emit light of the same wavelength, with each set emitting light of a different wavelength from another set. In this case, various filters may be used to transmit light to the detectors. Note that in some applications, such as chemical sensors, only a few tens of individual devices may be required, while in other applications, such as industrial lighting, thousands to millions of individual lighting may be required.

The microdischarge device **600** may also be combined to form a stack of individual microdischarge devices **618** and **620**, as shown in FIG. 9A. The microdischarge device **600** comprises a first microdischarge device **618**, including a first electrode **604**, insulator **606**, and second electrode **608** similar to the individual devices shown in FIG. 1 and a second microdischarge device **620** comprising another second electrode **616**, insulator **614**, and first electrode **612**. An insulating material **610** is disposed between the first microdischarge device **618** and the second microdischarge device **620**. The number of microdischarge devices present in the microdischarge device **600** is arbitrary, depending on the desired characteristics of the overall device. However, the cavity **602** of the microdischarge device **600** is formed by aligning the cavities of the individual microdischarge devices **618** and **620** for greater efficiency or by machining cavity **602** through layers **604-616** once the structure has been assembled.

Alternatively, as shown in FIG. 9B, one second electrode or first electrode for each device and the insulating material between the devices may be removed in forming a microdischarge device **700**. In this case, the first electrode **708** for the first microdischarge device **714** may serve as the second electrode for the second microdischarge device **716**. Thus, the structure of the microdischarge device **700** may be: second electrode₁ **704**, insulator₁ **706**, first electrode₁/second electrode₂ **708**, insulators₂ **710**, first electrode₂/second electrode₃ **712**, etc. . . ., with the cavities **702** aligned. Similarly, any of the microdischarge devices of the preceding embodiments may be stacked. In another embodiment (not shown) the microdischarge devices may be essentially back-to-back, i.e. the second electrode for the first microdischarge device may serve as the second electrode for the next microdischarge device or the first electrode for the first microdischarge device may serve as the first electrode for the next microdischarge device.

The microdischarge devices **600** and **700** may be fabricated in a manner similar to that given above for the individual microdischarge devices in the above embodiments, i.e., fabrication of the microdischarge device **700** may be relatively simple in an embodiment in which the layers are successively stacked: second electrode₁ **704**, insulator₁ **706**, first electrode₁/second electrode₂ **708**, insulator₂ **710**, and first electrode₂/second electrode₃ **712**.

The cavity **702** may be formed either in each layer individually before stacking the layers or after the layers have been stacked. The cavity **702** of the microdischarge devices **600** and **700** may be filled with the selected gas and then sealed. For example, the microdischarge device **700** may be positioned in a vacuum chamber, the chamber evacuated and then backfilled with the selected gas, and the cavity **702** sealed. A microdischarge device having a screen electrode or optically transmissive conducting film may additionally require mechanical assembly of the layers in a vacuum chamber that has been backfilled with the selected gas to permit the gas to fill the cavity of each individual microdischarge device.

One application using the microdischarge device **600** and **700** is a multi-stage structure for the remediation of toxic gases. This application entails flowing a gas that is environmentally hazardous or toxic through a series of microdischarges in the cavity **602** to break down the gas into benign products. Alternatively, the products of the gas discharge can be reacted with a titration gas (O₂, N₂, etc.) to produce a benign product rather than being completely broken down. In this application, the flow of the hazardous/toxic gas through the cavity **602** is imperative, and thus, the microdischarge device **600** and **700** would not be sealed by a laminate. Similarly, the individual microdischarge devices **618** and **620** would not be sealed by a conducting film disposed between the succeeding dielectric layers (although a screen electrode may still be disposed between the succeeding microdischarge devices **618** and **620**).

The microdischarge device **600** shown in FIG. 9A is also ideally suited for realizing a microlaser. Additional components (not shown) that are well known in the art, such as a mirror set, may be used to realize the microlaser. The stack of individual microdischarge devices **618** and **620** are aligned such that the discharge axes are coincident. These microlasers can generate ultraviolet (N₂ rare gas halide excimers), visible, or infrared radiation that may be used in materials processing or atmospheric diagnostic applications.

As mentioned before, while one focus of the present invention has been generally toward a flexible microdischarge device, some applications may not require flexibility, e.g., custom lighting, gas chromatography, and lasers. Benefits are conferred in these applications by the use of a thin insulator between the second electrode and first electrode other than silicon. The use of a thin insulator reduces the thickness of the various devices and additionally decreases the material and fabrication costs of the microdischarge device compared with conventional microdischarge devices using silicon (for example, which must be etched to form the cavity). The lack of necessity of flexibility for these applications allows some of the materials used in the microdischarge devices described above to include more rigid, yet inexpensive materials. For example, in some applications the second electrode or first electrode may be constructed of amorphous or polycrystalline silicon instead of metal. Similarly, the insulator sandwiched between the second electrode and first electrode may be an undoped or low doped semiconductor. For example, silicon with a doping of 10¹⁵ cm⁻³ or less may be sufficient to form an insulator. Additionally, material to seal the cavity or the supporting surface for the conducting film that replaces the metal second electrode may be glass rather than a plastic or resin. Although Si is generally used as the preferred material, any semiconductor material, such as group IV (Ge, diamond), III-V (GaAs, InP) and II-VI (ZnSe) materials, may also be used.

While the present invention has been described with reference to specific embodiments, the description is illustrative of the invention and not to be construed as limiting the invention.

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Various modifications and applications may occur to those skilled in the art without departing from the true spirit and scope of the invention as defined in the appended claims.

What is claimed is:

1. A method of fabricating an array of microdischarge devices, the method comprising:

positioning a multi-layer dielectric layer thin sheet with respect to a first thin electrode, wherein said step of positioning comprises depositing or plating the first thin electrode as a unitary electrode;

joining a second electrode thin sheet on the multi-layer dielectric layer thin sheet;

providing an array of microcavities through at least a portion of the multi-layer dielectric layer sheet within an area corresponding to said first electrode, each of said microcavities defining an empty volume for containing gas, each of said microcavities having walls defined by at said at least a portion of the multi-layer dielectric thin sheet;

filling the empty volumes in the microcavities with a gas, wherein said filling the empty volumes in the microcavities with a gas entirely fills the empty volumes; and sealing the gas in the microcavities.

2. The method of claim 1, wherein the multi-layer dielectric layer thin sheet comprises a polymer.

3. The method of claim 1, wherein the multi-layer dielectric layer thin sheet comprises an oxide film.

4. The method of claim 3, wherein the multi-layer dielectric layer thin sheet further comprises a nitride film.

5. The method of claim 1, wherein the multi-layer dielectric layer thin sheet comprises a nitride film.

6. The method of claim 1, wherein said step of positioning comprises spin-coating the multi-layer dielectric layer thin sheet onto the first thin electrode.

7. The method of claim 1, wherein the multi-layer dielectric layer thin sheet comprises multiple layers of different materials.

8. The method of claim 1, wherein said step of sealing comprises laminating the array of microdischarge devices to seal the devices.

9. The method of claim 8, wherein said laminating comprises laminating a plastic sheet on both sides of the array of microdischarge devices to seal the devices.

10. The method of claim 1, wherein said step of sealing comprises hard sealing the array of microdischarge devices to a quartz window to seal the devices.

11. A method of fabricating an array of microdischarge devices, the method comprising:

positioning a multi-layer dielectric layer thin sheet with respect to a first thin electrode;

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joining a second electrode thin sheet on the multi-layer dielectric layer thin sheet;

providing an array of microcavities through at least a portion of the multi-layer dielectric layer thin sheet;

filling the microcavities with a gas; and

sealing the gas in the microcavities, wherein each of the multi-layer dielectric layer thin sheet, the first thin electrode and the second electrode thin sheet have a thickness of less than about 100 μm .

12. The method of claim 11, wherein the first thin electrode has a thickness in the range of about 10 \AA -10 μm .

13. The method of claim 12, wherein the second electrode thin sheet has a thickness in the range of about 50 \AA -10 μm .

14. A method of fabricating an array of microdischarge devices, the method comprising:

providing a thin dielectric layer sheet,

providing an array of microcavities through at least a portion of the dielectric layer sheet, each of said microcavities defining an empty volume for containing gas, each of said microcavities having walls defined by said at least a portion of the dielectric layer sheet;

disposing a first electrode as a unitary film of conducting material on the dielectric layer sheet to surround rims of a plurality of microcavities in the array of microcavities; providing a second electrode sheet;

joining the dielectric layer sheet with first electrode and second electrode sheet together;

filling the empty volumes in the microcavities with a gas, wherein said filling the empty volumes in the microcavities with a gas entirely fills the empty volumes; and sealing the gas in the microcavities.

15. The method of claim 14, wherein said step of disposing comprises depositing or plating the first electrode as a film on the dielectric layer sheet.

16. The method of claim 14, wherein the dielectric layer sheet comprises a multi-layer dielectric layer sheet of different materials.

17. The method of claim 16, wherein the multi-layer dielectric sheet comprises an oxide film and a nitride film.

18. The method of claim 16, wherein the multi-layer dielectric sheet comprises a polymer.

19. The method of claim 14, wherein said step of sealing comprises laminating the array of microdischarge devices to seal the devices.

20. The method of claim 19, wherein said laminating comprises laminating a plastic sheet on both sides of the array of microdischarge devices to seal the devices.

21. The method of claim 14, wherein said step of sealing comprises hard sealing the array of microdischarge devices to a quartz window to seal the devices.

* * * * *

UNITED STATES PATENT AND TRADEMARK OFFICE
CERTIFICATE OF CORRECTION

PATENT NO. : 8,221,179 B2
APPLICATION NO. : 11/981412
DATED : July 17, 2012
INVENTOR(S) : Eden et al.

Page 1 of 2

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Title Page:

(60) Related Application Data:

Line 4 Delete “6,867,648” and insert --6,867,548-- therefor.

(56) References Cited:

Page 2, right column
Other Publications, line 9 Delete “Replicatioin” and insert --Replication-- therefor.

(57) Abstract:

Line 1 Delete “defines an empty volume formed in”.

Line 2 Delete “has its walls defined by the insulator 108 and”.

Lines 4-5 Delete “104, in which case the first electrode and/or second electrode also define the walls of the cavity 102” and insert --104-- therefor.

Lines 9-10 After “gas” delete “that contacts the cavity walls, fills the entire cavity 102 and is”.

In the Specification:

Col. 2, line 44 Delete “position” and insert --positioned-- therefor.

Col. 2, line 51 Delete the second occurrence of “less than”.

Signed and Sealed this
Thirteenth Day of August, 2013



Teresa Stanek Rea
Acting Director of the United States Patent and Trademark Office

CERTIFICATE OF CORRECTION (continued)

Page 2 of 2

U.S. Pat. No. 8,221,179 B2

Col. 3, line 24	Delete “position” and insert --positioned-- therefor.
Col. 3, line 31	Delete the second occurrence of “less than”.
Col. 5, line 21	After “The cavity 102” insert --defines an empty volume formed in--.
Col. 5, line 21	After “insulator 108” insert --has its walls defined by the insulator 108 and--.
Col. 5, line 23	After “electrode 104” insert --, in which case the first electrode and/or second electrode also define the walls of the cavity 102--.
Col. 5, line 26	After “gas” insert --that contacts the cavity walls, fills the entire cavity 102 and is--.
Col. 10, line 32	Between “lifetime” and “the” insert --of--.